

DMN4035L-13 Datasheet

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| DiGi Electronics Part Number | DMN4035L-13-DG |
|------------------------------|---|
| Manufacturer | Diodes Incorporated |
| Ianufacturer Product Number | DMN4035L-13 |
| Description | MOSFET N-CH 40V 4.6A SOT23 |
| Detailed Description | N-Channel 40 V 4.6A (Ta) 720mW Surface Mount SO T-23-3 |
| | |

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Purchase and inquiry

| Manufacturer Product Number: | Manufacturer: |
|---|---|
| DMN4035L-13 | Diodes Incorporated |
| Series: | Product Status: |
| - | Active |
| FET Type: | Technology: |
| N-Channel | MOSFET (Metal Oxide) |
| Drain to Source Voltage (Vdss): | Current - Continuous Drain (Id) @ 25°C: |
| 40 V | 4.6A (Ta) |
| Drive Voltage (Max Rds On, Min Rds On): | Rds On (Max) @ ld, Vgs: |
| 4.5V, 10V | 42mOhm @ 4.3A, 10V |
| Vgs(th) (Max) @ ld: | Gate Charge (Qg) (Max) @ Vgs: |
| 3V @ 250µA | 12.5 nC @ 10 V |
| Vgs (Max): | Input Capacitance (Ciss) (Max) @ Vds: |
| ±20V | 574 pF @ 20 V |
| FET Feature: | Power Dissipation (Max): |
| - | 720mW |
| Operating Temperature: | Mounting Type: |
| -55°C ~ 150°C (TJ) | Surface Mount |
| Supplier Device Package: | Package / Case: |
| SOT-23-3 | TO-236-3, SC-59, SOT-23-3 |
| Base Product Number: | |
| DMN4035 | |

Environmental & Export classification

| RoHS Status: | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant | 1 (Unlimited) |
| REACH Status: | ECCN: |
| REACH Unaffected | EAR99 |
| HTSUS: | |
| 8541.21.0095 | |





DMN4035L

Product Summary

| BV _{DSS} | R _{DS(ON)} max | I _D max |
|-------------------|-------------------------------|--------------------|
| | 42mΩ @ V _{GS} = 10V | 4.6A |
| 40V | 52mΩ @ V _{GS} = 4.5V | 4.1A |

N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Input Capacitance

Mechanical Data

Case: SOT23

- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e.: parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please refer to the related automotive grade (Q-suffix) part. A listing can be found at

https://www.diodes.com/products/automotive/automotiveproducts/.

- This part is qualified to JEDEC standards (as references in AEC-Q) for High Reliability.
 - https://www.diodes.com/quality/product-definitions/

UL Flammability Classification Rating 94V-0

Moisture Sensitivity: Level 1 per J-STD-020

Solderable per MIL-STD-202, Method 208 3

Terminals Connections: See Diagram Below

An Automotive-Compliant Part is Available Under Separate Datasheet (DMN4035LQ)

Case Material: Molded Plastic, "Green" Molding Compound.

Terminals: Finish — Matte Tin Annealed over Copper Leadframe.

Description and Applications

This MOSFET is designed to minimize the on-state resistance (RDS(ON)) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

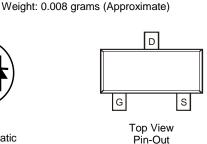
- Battery Charging
- Power Management Functions
- DC-DC Converters
- Portable Power Adaptors

SOT23





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Internal Schematic

Ordering Information (Note 4)

| Part Number | Case | Packaging |
|-------------|-------|-------------------|
| DMN4035L-7 | SOT23 | 3000/Tape & Reel |
| DMN4035L-13 | SOT23 | 10000/Tape & Reel |

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

Notes:

| Dat | te Code Ke | €Y | | [35L | |] | Y Y | M = Date 0 or $\overline{Y} = Ye$ | uct Type Ma Code Markii ar (ex: G = 2 (ex: 9 = Sep | ng 2019) | | | |
|-----|------------|------|-----|----------|------|------|--------|--------------------------------------|---|-------------|-----|-----|------|
| | Year | 2019 | 20 | 20 | 2021 | 2022 | 20 | 23 | 2024 | 2025 | 20 |)26 | 2027 |
| | Code | G | ł | 4 | | J | | < | L | М | | N | 0 |
| | Month | Jan | Feb | Mar | Apr | Мау | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| | Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | N | D |



Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit | | |
|---|--|------------------|------------|-----|---|
| Drain-Source Voltage | | VDSS | 40 | V | |
| Gate-Source Voltage | | V _{GSS} | ±20 | V | |
| Continuous Drain Current (Note 6) V_{GS} = 10V | T _A = +25°C T _A = +70°C | ID | 4.6 3.7 | А | |
| Maximum Body Diode Forward Current (Note 6) | | | ls | 1.5 | А |
| Pulsed Drain Current (10µs Pulse, Duty Cycle = 1% | Ідм | 25 | А | | |
| Pulsed Source Current (10µs Pulse, Duty Cycle = 1 | %) | | lsм | 25 | А |

Thermal Characteristics

| Characteristic | Symbol | Value | Unit | |
|--|--------------|-----------------------------------|-------------|------|
| Power Dissipation (Note 5) | | PD | 0.72 | W |
| Thermal Resistance, Junction to Ambient (Note 5) | Steady State | Reja | 171 | °C/W |
| Power Dissipation (Note 6) | · | PD | 1.4 | W |
| Thermal Resistance, Junction to Ambient (Note 6) | Steady State | Reja | 93 | °C/W |
| Operating and Storage Temperature Range | · | T _J , T _{STG} | -55 to +150 | °C |

Electrical Characteristics (@TA = +25°C, unless otherwise specified.)

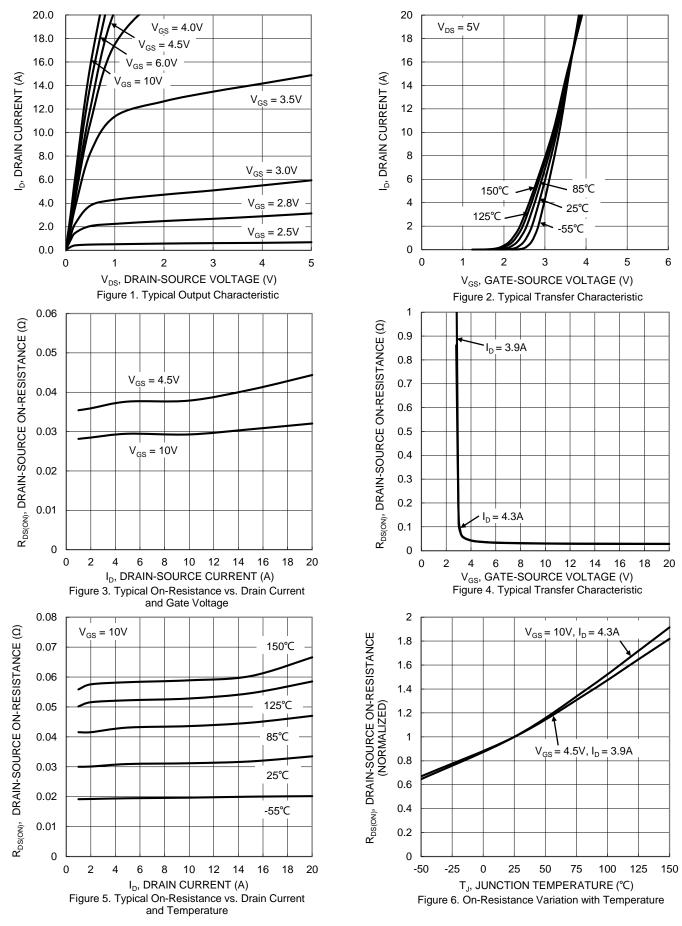
| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition |
|--|---------------------|-----|------|------|-------|--|
| OFF CHARACTERISTICS (Note 7) | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 40 | _ | | V | $V_{GS} = 0V, I_D = 250 \mu A$ |
| Zero Gate Voltage Drain Current | IDSS | _ | _ | 1 | μA | $V_{DS} = 40V, V_{GS} = 0V$ |
| Gate-Source Leakage | lgss | _ | _ | ±100 | nA | $V_{GS} = \pm 20V, V_{DS} = 0V$ |
| ON CHARACTERISTICS (Note 7) | | | • | • | • | · |
| Gate Threshold Voltage | V _{GS(TH)} | 1 | — | 3 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ |
| Static Drain-Source On-Resistance | Descent | _ | 30 | 42 | mΩ | Vgs = 10V, ID = 4.3A |
| Static Drain-Source On-Resistance | RDS(ON) | _ | 40 | 52 | 11152 | VGS = 4.5V, ID = 3.9A |
| Diode Forward Voltage | V _{SD} | | 0.7 | 1.1 | V | V _{GS} = 0V, I _S = 1.25A |
| DYNAMIC CHARACTERISTICS (Note 8) | • | | | | | - |
| Input Capacitance | Ciss | _ | 574 | _ | | $V_{DS} = 20V, V_{GS} = 0V,$ f = 1MHz |
| Output Capacitance | Coss | _ | 87.8 | _ | pF | |
| Reverse Transfer Capacitance | Crss | _ | 38.7 | _ | | |
| Gate Resistance | Rg | _ | 1.6 | | Ω | $V_{DS} = 0V, V_{GS} = 0V, f = 1MHz$ |
| Total Gate Charge (V _{GS} = 4.5V) | Qg | _ | 5.9 | | | |
| Total Gate Charge (V _{GS} = 10V) | Qg | | 12.5 | | nC | |
| Gate-Source Charge | Q _{gs} | | 1.7 | | nc | $V_{DS} = 20V, I_D = 3.9A$ |
| Gate-Drain Charge | Q _{gd} | | 2.2 | | | |
| Turn-On Delay Time | tD(ON) | | 3.1 | | | |
| Turn-On Rise Time | t _R | | 2.6 | _ | | $V_{DD} = 20V, V_{GS} = 10V,$ |
| Turn-Off Delay Time | t _{D(OFF)} | | 15 | | ns | $R_L = 20\Omega, R_G = 6\Omega$ |
| Turn-Off Fall Time | tF | _ | 5.5 | _ | 1 | |
| Reverse Recovery Time | trr | _ | 6.5 | _ | ns | |
| Reverse Recovery Charge | Q _{RR} | _ | 1.2 | | nC | IF = 3.9A, di/dt = 500A/μs |

Notes:

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
6. Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
7. Short duration pulse test used to minimize self-heating effect.
8. Guaranteed by design. Not subject to product testing.

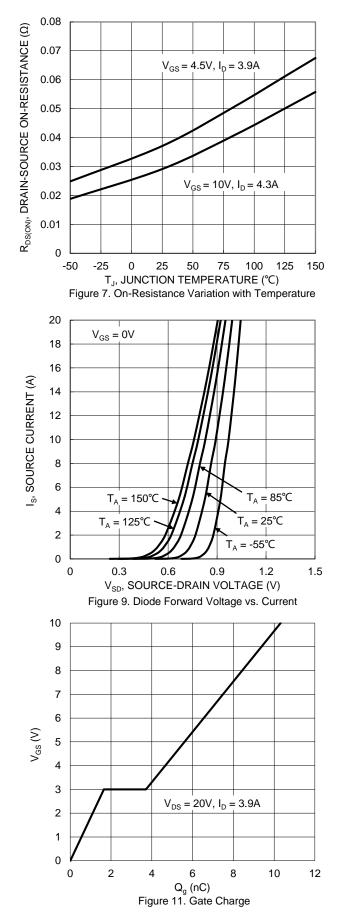


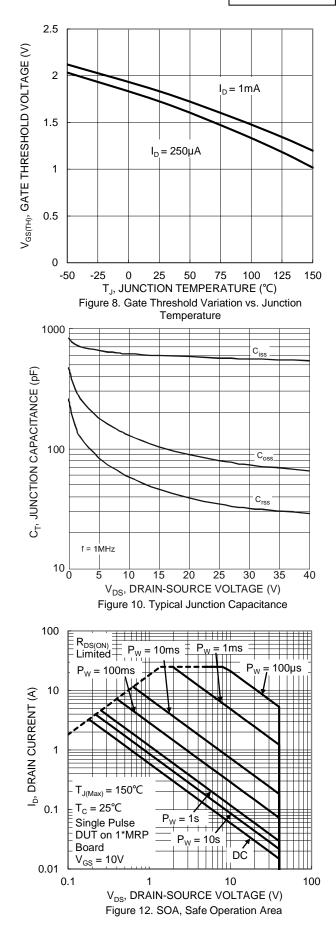
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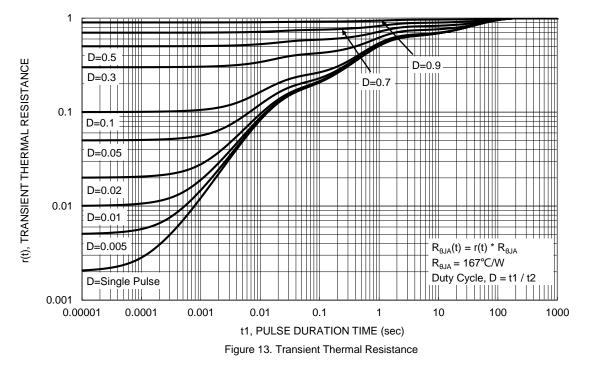
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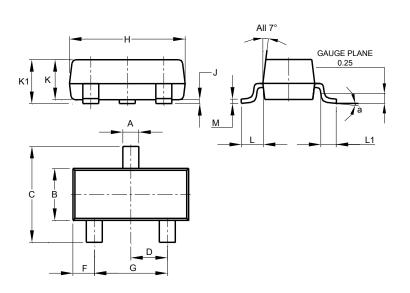
SOT23



DMN4035L

Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

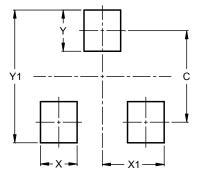


| | SOT23 | | | | | | | |
|-----|--------|---------|-------|--|--|--|--|--|
| Dim | Min | Max | Тур | | | | | |
| Α | 0.37 | 0.51 | 0.40 | | | | | |
| В | 1.20 | 1.40 | 1.30 | | | | | |
| С | 2.30 | 2.50 | 2.40 | | | | | |
| D | 0.89 | 1.03 | 0.915 | | | | | |
| F | 0.45 | 0.60 | 0.535 | | | | | |
| G | 1.78 | 2.05 | 1.83 | | | | | |
| н | 2.80 | 3.00 | 2.90 | | | | | |
| J | 0.013 | 0.10 | 0.05 | | | | | |
| K | 0.890 | 1.00 | 0.975 | | | | | |
| K1 | 0.903 | 1.10 | 1.025 | | | | | |
| L | 0.45 | 0.61 | 0.55 | | | | | |
| L1 | 0.25 | 0.55 | 0.40 | | | | | |
| М | 0.085 | 0.150 | 0.110 | | | | | |
| а | 0° | 8° | | | | | | |
| All | Dimens | ions in | mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SOT23



| Dimensions | Value (in mm) | | | |
|------------|---------------|--|--|--|
| С | 2.0 | | | |
| Х | 0.8 | | | |
| X1 | 1.35 | | | |
| Y | 0.9 | | | |
| Y1 | 2.9 | | | |



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